SSM&P Docket No.: 16818

IBM Docket No.: YOR920030293US1

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which THIN BURIED OXIDES BY LOW-DOSE OXYGEN IMPLANTATION INTO MODIFIED SILICON

<u>x</u> is attached hereto.			
was filed on	as United States App	plication Number	
or PCT International Ap	plication Number		
and was amended on	(if appli	cable)	
I hereby state that I have revi the claims, as amended by any a	ewed and understand the contouring	ants of the above identified specifi	cation, including
I acknowledge the duty to discloswith Title 37, Code of Federal	e information which is materia Regulations, Section 1.56.	l to the patentability of this applica	tion in accordance
any foreign application for pate	nt or inventor's certificate	of any PCT International application want day of the control of th	
time of the application	on which priority is claimed:		Priority Claimed
Prior Foreign Application (8) (Number)	on which priority is claimed: (Country)	(Day/Month/Year Filed)	Priority Claimed
Prior Foreign Application(s)	on which priority is claimed:	(Day/Month/Year Filed)	Priority Claimed
Prior Foreign Application(s) (Number)	(Country)	(Day/Month/Year Filed)	Priority Claimed Yes No
Prior Foreign Application(s) (Number)	(Country)	(Day/Month/Year Filed) (Day/Month/Year Filed)	Priority Claimed Yes No
Prior Foreign Application(s) (Number) (Number) I hereby claim the benefit unde	(Country) (Country) (Country) r 35 U.S.C. '119(e) of any Un	(Day/Month/Year Filed) (Day/Month/Year Filed)	Priority Claimed Yes No

(Status) (patented, pending, abandoned) I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that willful False statements may jeopardize the validity of the application or any patent

(Filing Date)

(Filing Date)

issued thereon. POWER OF ATTORNEY: As a named inventor I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration

Richard M. Ludwin (Reg. 33,010), Kevin M. Jordan (Reg. 40,277), Christopher A. Hughes (Reg. 26,914), John E. Hoel (Reg. 26,279), Joseph C. Redmond, Jr. (Reg. 18,753), Douglas W. Cameron (Reg. 31,596), Wan Yee Cheung (Reg. 42,410),

(Status) (patented, pending, abandoned)

number).

(Application Serial No.)

(Application Serial No.)

Thu Ann Dang (Reg. 41,544), Louis F. Herzberg (Reg. 41,500), Derek S. Jennings (Reg. 41,473), Stephen C. Kaufman (Reg. 29, 551), Daniel P. Morris (Reg. 32,053), Aliaon D. Mortinger (Reg. 39,306), Louis J. Percello (Reg. 33,206), Robert M. Trepp (Reg. 25,933), Gali H. Zarick (Reg. 43,303), Rafael A. Percz-Pineiro (Reg. 46,041).

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

Send Correspondence to: Steven Fischman, Scully, Scott, Murphy & Presser

400 Garden City Plaza, Garden City, New York 11530

Direct Telephone Calls to: Steven Fischman, (516) 742-4343

Kwang Su Choe			
Full name, of first inventor		,	
Loon hu thre	Conta		30, 2003
5 Wan hullhore	<u> </u>	noer	20,20
Inventor's Signature	/	Date	
a control Description	Cu Fundanam Chi	Wyonavi-De	South Kores 463-786
Sangrok-Woosung Apt. 323-905, Jungja-Dong 122, Boondang-	Gu, Sungnam-Sm,	Kyonger-De	Bodili Rolea 403-700
Residence	•		
Republic of Korea			
Citizenship			
CILIZONSHIP			
Same as Residence			
Post Office Address			•
Keith E. Fogel			
Full name of second inventor			
Inventor's Signature		Date	
4 June 1 and Mahadam Tales NV 10547			
4 Lucs Lane, Mohegan Lake, NY 10547			
Residence.	;		•
United States of America			
Citizenship			
CICISCUBILD			
Same as Residence			
Post Office Address			
1000 OTTIC IMMIOND			
Siegfried L. Maurer			
Full name of third inventor			
Inventor's Signature		Date	
26 Blueberry Lane, Stormville, New York 12582			
Residence			

United States of America		
Citizenship		
Same as Residence		
Post Office Address		
Ryan M. Mitchell		
Full name of fourth inventor		
Inventor's Signature	Date	
67 Picnic Woods Road, Clintondale, New York 12515		
Residence		
VESTMENCE		
United States of America		
Citizenship		
		• .
Same as Residence		
Post Office Address		
Devendra K. Sadana		
Full name of fifth inventor		•
Inventor's Signature	Date	
90 Sky Top Drive, Pleasantville, NY 10570		
Residence		
United States of America		
Citizenship		
Same as Residence		
Post Office Address		

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the specification of which (check one	e)		•
x is attached herato.			
was filed on	as United States App	lication Number	
or PCF International Applicat			
and was amended on	(if applie	able)	
I hereby state that I have reviewed a	ent referred to above.		
I acknowledge the duty to disclose in accordance with Title 37, Code of Fed	nformation which is mate deral Regulations, Secti	rial to the patentability of this on 1.56.	application in
I hereby claim foreign priority benefication(s) for patent or which designated at least one country by checking the box, any foreign application, having a filing date between	inventor's dertificate, y other than the United : lightion for natent or i	or §365(a) of any PCT Intermation States, listed below and have also eventor's certificate, or PCT Into	al application identified below, expational
Prior Foreign Application(s)			Priority Claimed
		(Day/Month/Year Filed)	Үев No
(Number)	(Country)	(Day/Month/Year Piled)	Yes No
I hereby claim the benefit under 35 t	J.S.C. §119(a) of any Co.	ited States provisional application	n(s) listed below.
(Application Number)	(Filing Date)		
(Application Number)	(Filing Date)		
I hereby claim the benefit under 35 to International application designating of the claims of this application is in the manner provided by the first material to the patentablity of this date of the prior application and the	y the United States, lis- not disclosed in the property paragraph of 35 U.S.C. § application as defined	ted below and, insofar as the subj lor United States, or PCT Internat 112, I acknowledge the duty to dis in 37 CPR \$1.55 which occurred be	ect matter of each ional application close information tween the filing
(Application Serial No.)			ng, abandoned)
(Application Serial No.)	(Filing Date)	(Status) (patented, pendi	ing, abandoned)
I hereby declare that all statements information and belief are believed that willful false statements and the Section 1001 of Title 18 of the Unite of the application or any patent issue	to be true; and further to like so made are punished States Code and that w	that these statements were made witable by fine or imprisonment, or i	th the knowledge both, under
POWER OF ATTORNEY: As a pamed invent this application and transact all bus registration number).	or I hereby appoint the liness in the Patent and	following attorney(s) and/or agent Trademark Office connected therew.	t(s) to prosecute ith (list name and
Richard M. Ludwin (Reg. 33,010), Kevi Hoel (Reg. 26,279), Joseph C. Redmond 42,410), Thu Ann Dang (Reg. 41,544), C. Kaufman (Reg. 29, 551), Daniel P. (Reg. 33,206), Robert M. Trepp (Reg.	, Jr. (Reg. 18,753), Dou Louis P. Herzberg (Reg. Morris (Reg. 32,053), Al	glas W. Cameron (Reg. 31,596), War 41,500), Derek S. Jennings (Reg. 4 dison D. Mortinger (Reg. 39,306), 1	Yee Cheung (Reg. 11,473), Staphen

46,041).

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Sand Correspondence to: Steven Fischman, Scully, Scott, Murphy & Presser 400 Garden City Plaza, Gardon City, New York 11530

Direct Telephone Calls to: Steven Fischman. (516) 742-4343

Kwang Su Choe	
Full name of first inventor	
Inventor's Signature	Date
Sangrok-Woosung Apt, 323-905, Jungia-Dong 122, Boondang-Gu, Sungni Residence	am-Shi, Kyonggi-Do, South Korea 463-786
Republic of Korea	
Citizenship	
Same as Residence Post Office Address	
Keith B. Pogol Full name of second inventor	
Inventor's Signature	Date
4 Lucs Lane, Mohegan Lake, NY 10547 Residence	
United States of America Citizenship	
Same as Residence	·
Post Office Address	
Slegfried // Maurer	
Full name of third inventor	
hale to he	9-30-03
Inventor's Signature	Date
26 Blueberry Lane, Stormville, New York 12582	
Residence	
United States of America Citizenship	
Same as Residence	
Post Office Address	

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SSM&P Docket No.: 16818 IBM Docket No.: YOR920030293US1

Ryan M. Mitchell	15M DOCKEL NO.: YOR9200302930S1
Full name of fourth inventor	9/30/03
Inversor's Signature	Date
67 Picnic Woods Road, Clintondale, New York 12515 Residence	
United States of America Citizenship	
Same as Residence Post Office Address	
Devendra K. Sadana Full name of fifth inventor,	
Daning Contains	9/37/03
90 Sky Top Drive, Pleasantville, NY 10570 Residence	
United States of America Citizenship	
Same as Residence Post Office Address	

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OW-DOSE OXYGEN IMPLANTA		•	:
the specification of which (chec	k one)		·
x is attached hereto.		Tication Number	·
was filed on	as United States App	,	
or PCT International App.	lication Number		•
and was amended on	(if applie	cable)	
	the conte	ents of the above identified speci	fication, including
I hereby state that I have revie the claims, as amended by any ar	ewed and understand the control mendment referred to above.	ents of the above identified speci	application in
I acknowledge the duty to disch	ore information which is made of Federal Regulations, Sect	erial to the patentability of this	365(b) of any
I hereby claim foreign priority	benefits under Title 35. Union to inventor's certificate	ited States Code, §119(a)-(d) or § 656(a) of any PCT Internation of the states, listed helow and have all inventor's certificate, or PCT Internation on which priority is claimed	
Prior Foreign Application(s)			Yes No
	(Country)	(Day/Month/Year Filed)	XCA NO
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(Application Number)	(Filing Date)		
(Application Number)	(Filing Date)	and States Application(s), or \$365	s(c) of any PCT
of the claims of this applicat	tion is not disclosed in the	ted States Application(s), or §365 isted below and. insofar as the sprior United States, or PCT Inter. §112, I acknowledge the duty to add in 37 CFR §1.56 which occurred ernational filing date of this app	between the filing
		(Status) (patenced, p	BUGING, Spanonion,
(Application Serial No.)	(m. 1 ma - 10 man)	(Status) (patented, p	ending, abandoned)
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that willful false statements	and the like so made are pure the United States Code and the	n knowledge are true and that all er that these statements were made nishable by fine or imprisonment, at willful false statements may for	sopardize the validity
POWER OF ATTORNEY: As a name	ed inventor I hereby appoint all business in the Patent	the following attorney(s) and/or and Trademark Office connected the	
Richard M. Ludwin (Reg. 33.01	10), Kevin M. Jordan (Reg. 40, Redmond, Jr. (Reg. 18,753),	0,277), Christopher A. Hughos (Reg. Douglas W. Cameron (Reg. 31,596) Reg. 41,500), Derek S. Jennings (R Rg, Alison D. Mortinger (Reg. 39,30 rick (Reg. 43,303), Rafael A. Pere	Wan Yee Cheung (Reg. 41,473), Stephen

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400 Garden City Plaza, Garden City. New York 11530

Direct Telephone Calls to: Steven Piechman, (516) 742-4343

wang Su Choe ull name of first inventor	
III Hame or response	
	Date
eventor's Signature	Do South Korea 463-786
iventor's Signature angrok-Woosung Apt. 323-905, Jungja-Dong 122, Boondang-Gu, Sungnar	n-Shi, Kyonggi-Do, South Korea
angrok-Woosing Apr. 323-703, 3445	
esidence	
epublic of Korea	
itizenship	
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Same as Residence	
Post Office Address	
Keith B. Fogel	1 1
Full pame of second inventor	9/20/62
5/ TIN 9 AM	1/300
1 300 6	pare (
Inventor's Signature	
4 Lucs Lane, Mohegan Lake, NY 10547	
Residence	
United States of America	
Citizenship	
Same as Residence Post Office Address	
POBE CITICE MICEOR	
Siegfried L. Maurer	
Full name of third inventor	
	Date
Inventor's Signature	
26 Blueberry Lane, Stormville, New York 12582	
Residence	
United States of America	
Citizenship	
Same as Residence	
Post Office Address	

2

Ryan M. Mitchell Full name of fourth inventor		
Full name of rearrant and and		
	Date	
Inventor's Signature		
67 Picnic Woods Road, Clintondale, New York 12515		
Residence		
Kealdence	_	
United States of America		
Citizenship		
C1C12G:0:P		
Same as Residence		
Post Office Address		
Devendra K. Sadana		
Full name of fifth inventor		
	Date	
Inventor's Signature		
90 Sky Top Drive, Pleasantville, NY 10570		
90 Sky Top Drive, Picadone		
Residence		
United States of America		
United States of		
Citizenship		
Same as Residence		
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